

## NPN POWER SILICON TRANSISTOR

Qualified per MIL-PRF-19500/ 466

### Devices

2N5683

2N5684

### Qualified Level

JAN  
JANTX  
JANTXV

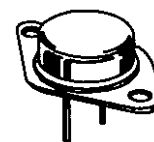
### MAXIMUM RATINGS

| Ratings                                        | Symbol         | 2N5683      | 2N5684 | Unit               |
|------------------------------------------------|----------------|-------------|--------|--------------------|
| Collector-Emitter Voltage                      | $V_{CEO}$      | 60          | 80     | Vdc                |
| Collector-Base Voltage                         | $V_{CBO}$      | 60          | 80     | Vdc                |
| Emitter-Base Voltage                           | $V_{EBO}$      | 5.0         |        | Vdc                |
| Base Current                                   | $I_B$          | 15          |        | Adc                |
| Collector Current                              | $I_C$          | 50          |        | Adc                |
| Total Power Dissipation <sup>(1)</sup>         |                |             |        |                    |
| @ $T_C = 25^{\circ}\text{C}$                   | $P_T$          | 300         |        | W                  |
| @ $T_C = 100^{\circ}\text{C}$                  |                | 171         |        | W                  |
| Operating & Storage Junction Temperature Range | $T_J, T_{stg}$ | -65 to +200 |        | $^{\circ}\text{C}$ |

### THERMAL CHARACTERISTICS

| Characteristics                      | Symbol          | Max.  | Unit                 |
|--------------------------------------|-----------------|-------|----------------------|
| Thermal Resistance, Junction-to-Case | $R_{\theta JC}$ | 0.584 | $^{\circ}\text{C/W}$ |

1) Derate linearly 1.715 W/ $^{\circ}\text{C}$  between  $T_C = +25^{\circ}\text{C}$  and  $T_C = +200^{\circ}\text{C}$



TO-3\*  
(TO-204AA)

\*See appendix A for package outline

### ELECTRICAL CHARACTERISTICS ( $T_C = 25^{\circ}\text{C}$ unless otherwise noted)

| Characteristics | Symbol | Min. | Max. | Unit |
|-----------------|--------|------|------|------|
|-----------------|--------|------|------|------|

### OFF CHARACTERISTICS

|                                                                                                                                                |                  |               |            |                 |
|------------------------------------------------------------------------------------------------------------------------------------------------|------------------|---------------|------------|-----------------|
| Collector-Emitter Breakdown Voltage<br>$I_C = 200 \text{ mAdc}$                                                                                | 2N5683<br>2N5684 | $V_{(BR)CEO}$ | 60<br>80   | Vdc             |
| Collector-Emitter Cutoff Current<br>$V_{CE} = 30 \text{ Vdc}$<br>$V_{CE} = 40 \text{ Vdc}$                                                     | 2N5683<br>2N5684 | $I_{CEO}$     | 5.0<br>5.0 | $\mu\text{Adc}$ |
| Collector-Emitter Cutoff Current<br>$V_{CE} = 60 \text{ Vdc}, V_{BE} = 1.5 \text{ Vdc}$<br>$V_{CE} = 80 \text{ Vdc}, V_{BE} = 1.5 \text{ Vdc}$ | 2N5683<br>2N5684 | $I_{CEX}$     | 5.0<br>5.0 | $\mu\text{Adc}$ |
| Collector-Base Cutoff Current<br>$V_{CB} = 60 \text{ Vdc}$<br>$V_{CB} = 80 \text{ Vdc}$                                                        | 2N5683<br>2N5684 | $I_{CBO}$     | 5.0<br>5.0 | $\mu\text{Adc}$ |
| Emitter-Base Cutoff Current<br>$V_{EB} = 5.0 \text{ Vdc}$                                                                                      |                  | $I_{EBO}$     | 5.0        | $\mu\text{Adc}$ |

**ELECTRICAL CHARACTERISTICS (con't)**

| Characteristics | Symbol | Min. | Max. | Unit |
|-----------------|--------|------|------|------|
|-----------------|--------|------|------|------|

**ON CHARACTERISTICS <sup>(2)</sup>**

|                                                                                                                                                                                                   |                      |                 |            |     |
|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------|-----------------|------------|-----|
| Forward-Current Transfer Ratio<br>I <sub>C</sub> = 5.0 Adc, V <sub>CE</sub> = 2.0 Vdc<br>I <sub>C</sub> = 25 Adc, V <sub>CE</sub> = 2.0 Vdc<br>I <sub>C</sub> = 50 Adc, V <sub>CE</sub> = 5.0 Vdc | h <sub>FE</sub>      | 30<br>15<br>5.0 | 60         |     |
| Collector-Emitter Saturation Voltage<br>I <sub>C</sub> = 25 Adc, I <sub>B</sub> = 2.5 Adc<br>I <sub>C</sub> = 50 Adc, I <sub>B</sub> = 10 Adc                                                     | V <sub>CE(sat)</sub> |                 | 1.0<br>5.0 | Vdc |
| Base-Emitter Saturation Voltage<br>I <sub>C</sub> = 25 Adc, I <sub>B</sub> = 2.5 Adc                                                                                                              | V <sub>BE(sat)</sub> |                 | 2.0        | Vdc |
| Base-Emitter Voltage<br>I <sub>C</sub> = 25 Adc, V <sub>CE</sub> = 2.0 Vdc                                                                                                                        | V <sub>BE(on)</sub>  |                 | 2.0        | Vdc |

**DYNAMIC CHARACTERISTICS**

|                                                                                                                                                          |                  |     |       |    |
|----------------------------------------------------------------------------------------------------------------------------------------------------------|------------------|-----|-------|----|
| Magnitude of Common Emitter Small-Signal Short-Circuit Forward Current Transfer Ratio<br>I <sub>C</sub> = 5.0 Adc, V <sub>CE</sub> = 10 Vdc, f = 1.0 MHz | h <sub>fe</sub>  | 2.0 | 20    |    |
| Small-Signal Short-Circuit Forward Current Transfer Ratio<br>I <sub>C</sub> = 10 Adc, V <sub>CE</sub> = 5.0 Vdc, f = 1.0 kHz                             | h <sub>fe</sub>  | 15  |       |    |
| Output Capacitance<br>V <sub>CB</sub> = 10 Vdc, I <sub>E</sub> = 0, 0.1 MHz ≤ f ≤ 1.0 MHz                                                                | C <sub>obo</sub> |     | 2,000 | pF |

**SWITCHING CHARACTERISTICS**

|                                                                                                                 |                  |  |     |    |
|-----------------------------------------------------------------------------------------------------------------|------------------|--|-----|----|
| Turn-On Time<br>V <sub>CC</sub> = 30 Vdc; I <sub>C</sub> = 25 Adc; I <sub>B</sub> = 2.5 Adc                     | t <sub>on</sub>  |  | 1.5 | μs |
| Turn-Off Time<br>V <sub>CC</sub> = 30 Vdc; I <sub>C</sub> = 25 Adc; I <sub>B1</sub> = I <sub>B2</sub> = 2.5 Adc | t <sub>off</sub> |  | 3.0 | μs |

**SAFE OPERATING AREA**

|                                                                                                    |  |  |  |  |
|----------------------------------------------------------------------------------------------------|--|--|--|--|
| <b>DC Tests</b><br>T <sub>C</sub> = +25°C, 1 Cycle, t = 1.0 s                                      |  |  |  |  |
| <b>Test 1</b><br>V <sub>CE</sub> = 6.0 Vdc, I <sub>C</sub> = 50 Adc                      All Types |  |  |  |  |
| <b>Test 2</b><br>V <sub>CE</sub> = 30 Vdc, I <sub>C</sub> = 10 Adc                      All Types  |  |  |  |  |
| <b>Test 3</b><br>V <sub>CE</sub> = 50 Vdc, I <sub>C</sub> = 560 mAdc                      2N5683   |  |  |  |  |
| V <sub>CE</sub> = 60 Vdc, I <sub>C</sub> = 640 mAdc                      2N5684                    |  |  |  |  |

(2) Pulse Test: Pulse Width = 300μs, Duty Cycle ≤ 2.0%.